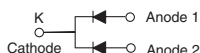


High Current Density Surface Mount Dual Common-Cathode Schottky Rectifier

eSMP™ Series



TO-277A (SMPC)



FEATURES

- Very low profile - typical height of 1.1 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

AUTOMOTIVE
GRADE
Available



RoHS
COMPLIANT
HALOGEN
FREE

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 4.0 A
V_{RRM}	30 V, 40 V
I_{FSM}	120 A
E_{AS}	20 mJ
V_F at $I_F = 4$ A	0.42 V
T_J max.	150 °C

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	SS8P3C	SS8P4C	UNIT
Device marking code		S83C	S84C	
Maximum repetitive peak reverse voltage	V_{RRM}	30	40	V
Maximum average forward rectified current (fig. 1)	total device	8.0		A
	per diode	4.0		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I_{FSM}	120		A
Non-repetitive avalanche energy at 25 °C, $I_{AS} = 2$ A per diode	E_{AS}	20		
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150		°C

SS8P3C, SS8P4C

Vishay General Semiconductor



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 2.0 A	T _A = 25 °C	V _F ⁽¹⁾	0.42	-	V
	I _F = 4.0 A			0.48	0.58	
	I _F = 2.0 A	T _A = 125 °C		0.32	-	
	I _F = 4.0 A			0.42	0.48	
Reverse current per diode	Rated V _R	T _A = 25 °C	I _R ⁽²⁾	130	300	μA
		T _A = 125 °C		26	35	mA
Typical junction capacitance per diode	4.0 V, 1 MHz		C _J	230	-	pF

Notes(1) Pulse test: 300 μs pulse width, 1 % duty cycle(2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise specified)				
PARAMETER	SYMBOL	SS8P3C	SS8P4C	UNIT
Typical thermal resistance per diode	R _{θJA} ⁽¹⁾	60		°C/W
	R _{θJL}	3		

Note

(1) Units mounted on recommended PCB 1 oz. pad layout

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SS8P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel
SS8P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel
SS8P4CHM3/86A ⁽¹⁾	0.10	86A	1500	7" diameter plastic tape and reel
SS8P4CHM3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel

Note

(1) Automotive grade

RATINGS AND CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

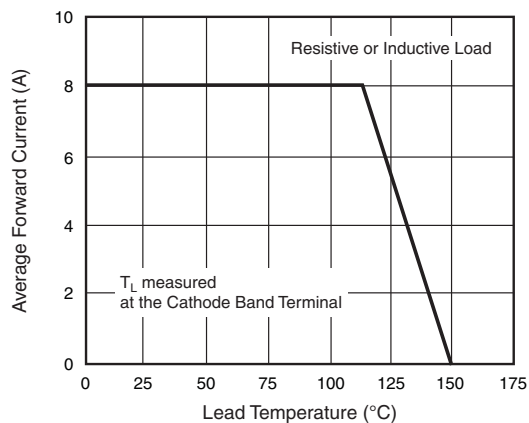


Fig. 1 - Maximum Forward Current Derating Curve

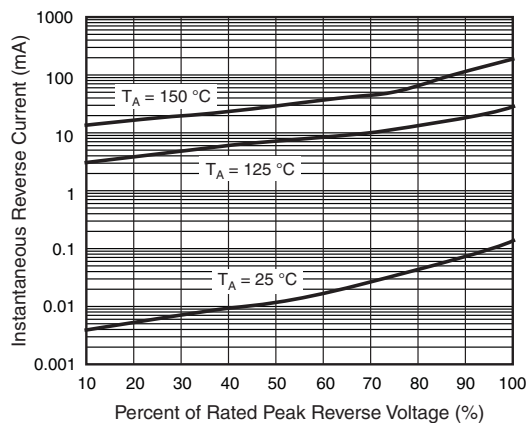


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

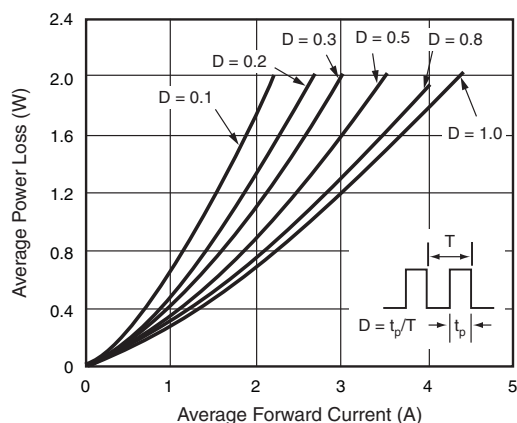


Fig. 2 - Forward Power Loss Characteristics Per Diode

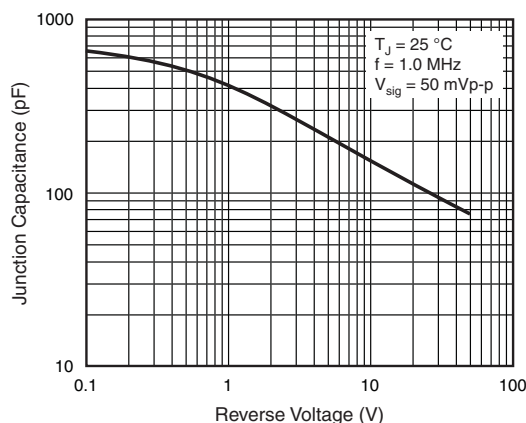


Fig. 5 - Typical Junction Capacitance Per Diode

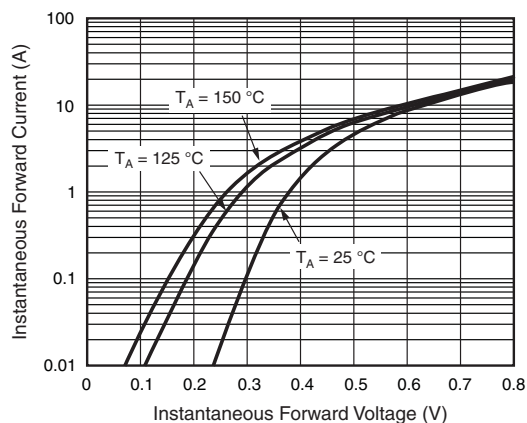


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

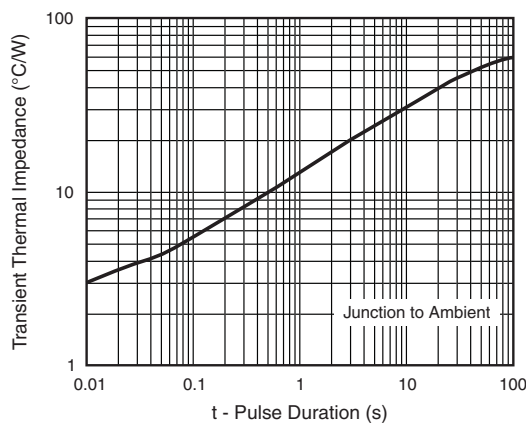
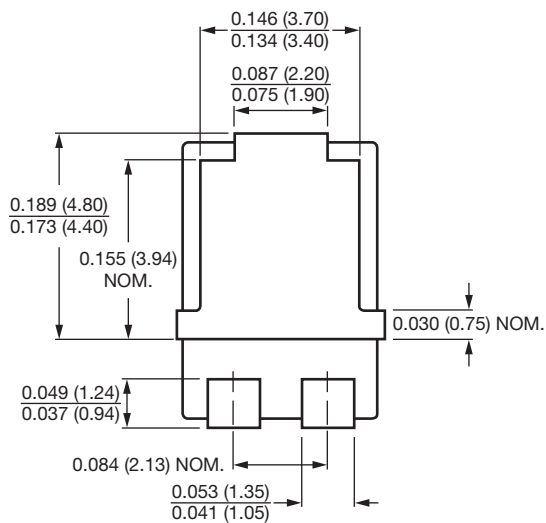
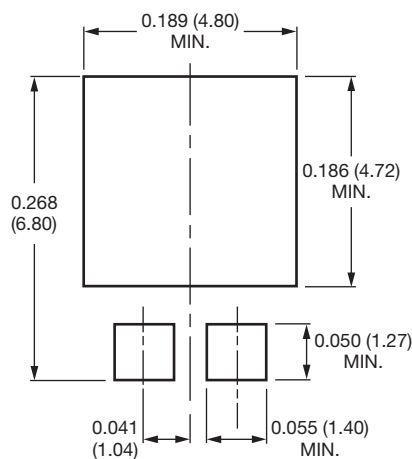


Fig. 6 - Typical Transient Thermal Impedance Per Diode

SS8P3C, SS8P4C

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**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)**TO-277A (SMPC)****Mounting Pad Layout**

Conform to JEDEC TO-277A



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